

1A, 50V - 1000V High Efficient Surface Mount Rectifiers

FEATURES

- Glass passivated chip junction
- Ideal for automated placement
- Low forward voltage drop
- Fast switching for high efficiency
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

MECHANICAL DATA

Case: DO-214AC (SMA)

Molding compound, UL flammability classification rating 94V-0

Moisture sensitivity level: level 1, per J-STD-020

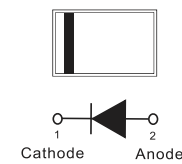
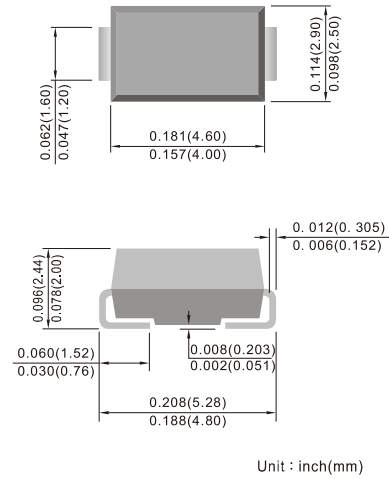
Terminal: Matte tin plated leads, solderable per JESD22-B102

Meet JESD 201 class 2 whisker test

Polarity: Indicated by cathode band

Weight: 0.06 g (approximately)

DO-214AC (SMA)



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T _A =25°C unless otherwise noted)										
PARAMETER	SYMBOL	US 1A	US 1B	US 1D	US 1F	US 1G	US 1J	US 1K	US 1M	UNIT
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	300	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	210	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	300	400	600	800	1000	V
Maximum average forward rectified current	I _{F(AV)}	1								A
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	30								A
Maximum instantaneous forward voltage (Note 1) @ 1 A	V _F	1.0		1.3		1.7			V	
Maximum reverse current @ rated V _R	I _R	5		50		150			μA	
		T _J =25°C		T _J =100°C		T _J =125°C				
Maximum reverse recovery time (Note 2)	t _{rr}	50				75			ns	
Typical junction capacitance (Note 3)	C _J	20				15			pF	
Typical thermal resistance	R _{θJA}	70								°C/W
Operating junction temperature range	T _J	- 55 to +150								°C
Storage temperature range	T _{STG}	- 55 to +150								°C

Note 1: Pulse test with PW=300μs, 1% duty cycle

Note 2: Reverse Recovery Test Conditions: I_F=0.5A, I_R=1.0A, I_{RR}=0.25A

Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

RATINGS AND CHARACTERISTICS CURVES

($T_A=25^{\circ}\text{C}$ unless otherwise noted)

FIG.1- MAXIMUM AVERAGE FORWARD CURRENT DERATING

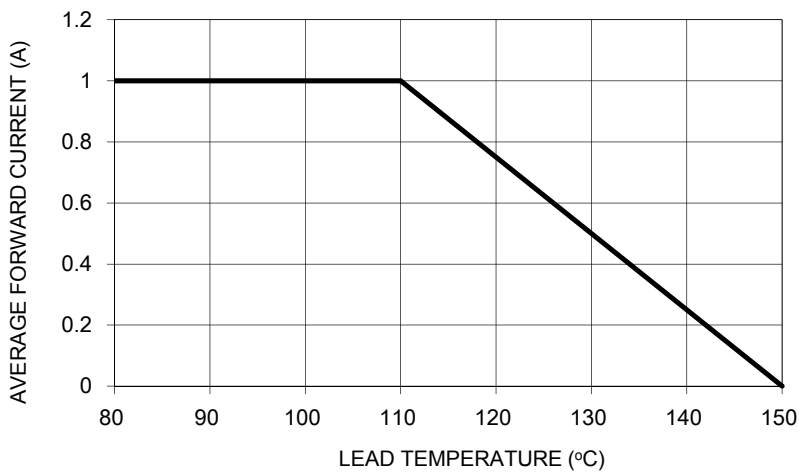


FIG. 2- TYPICAL REVERSE CHARACTERISTICS

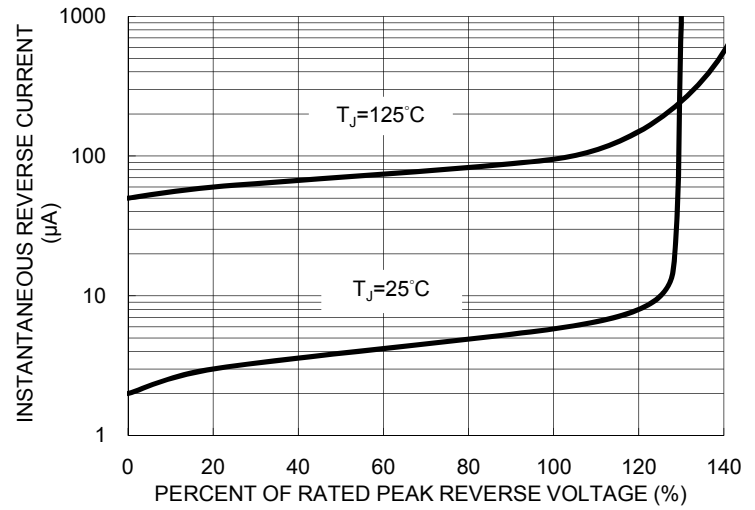


FIG. 3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

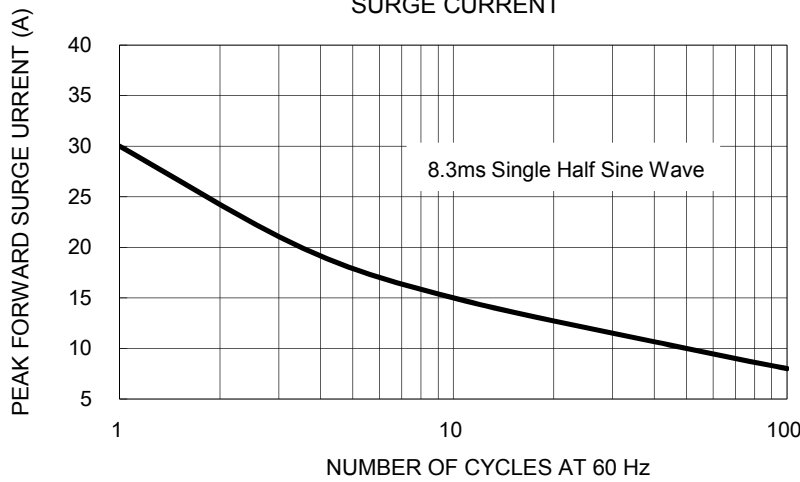


FIG. 4- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

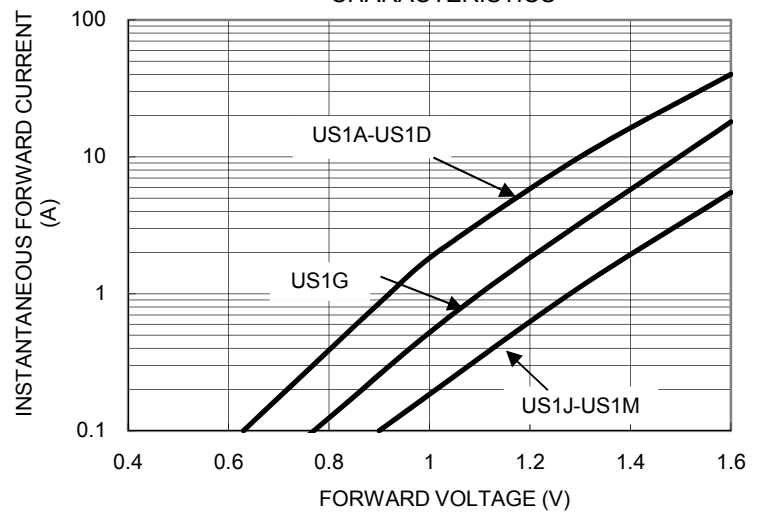


FIG. 5- TYPICAL JUNCTION CAPACITANCE

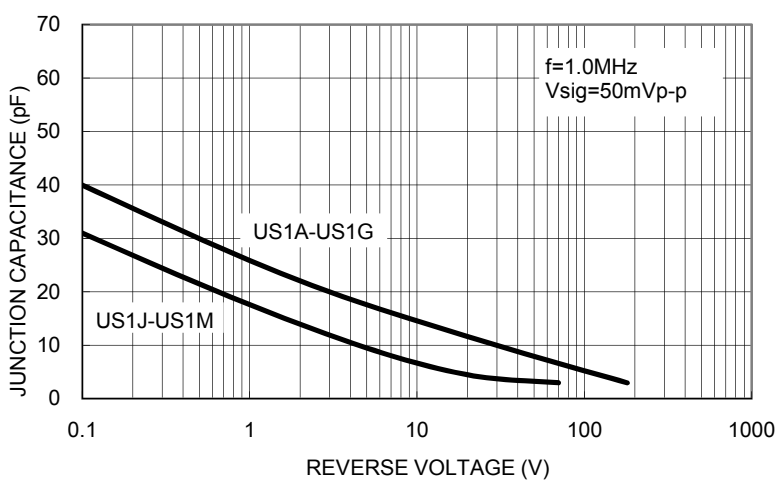


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

